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April 2016

FAN7171_F085
High-Current High-Side Gate Drive IC

Features

- Automotive qualified to AEC Q100
- Floating Channel for Bootstrap Operation to +600 V
- 4 A Sourcing and 4 A Sinking Current Driving Capability
- Common-Mode dv/dt Noise-Cancelling Circuit
- 3.3 V and 5 V Input Logic Compatible
- Output In-phase with Input Signal
- Under- Voltage Lockout for V_{BS}
- 25 V Shunt Regulator on V_{DD} and V_{BS}
- 8-Lead, Small Outline Package

Applications

- Common Rail Injection Systems
- DC-DC Converter
- Motor Drive (Electric Power Steering, Fans)

Related Product Resources

- *FAN7171_F085 Product Folder*
- *AN-6076 Design and Application Guide of Bootstrap Circuit for High-Voltage Gate-Drive IC*
- *AN-8102 200 Recommendations to Avoid Short Pulse Width Issues in HVIC Gate Driver Applications*
- *AN-9052 Design Guide for Selection of Bootstrap Components*
- *AN-4171 FAN7085 High-Side Gate Driver- Internal Recharge Path Design Considerations*

Description

The FAN7171_F085 is a monolithic high-side gate drive IC that can drive high-speed MOSFETs and IGBTs that operate up to +600 V. It has a buffered output stage with all NMOS transistors designed for high pulse current driving capability and minimum cross-conduction.

Fairchild's high-voltage process and common-mode noise-canceling techniques provide stable operation of the high-side driver under high-dv/dt noise circumstances. An advanced level-shift circuit offers high-side gate driver operation up to V_S=-9.8 V (typical) for V_{BS}=15 V.

The UVLO circuit prevents malfunction when V_{BS} is lower than the specified threshold voltage.

The high-current and low-output voltage-drop feature make this device suitable for sustaining switch drivers and energy-recovery switch drivers in automotive motor drive inverters, switching power supplies, and high-power DC-DC converter applications.

Figure 1. 8-Lead, SOIC, Narrow Body

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FAN7171M_F085	-40°C ~ 125°C	8-Lead, Small Outline Integrated Circuit (SOIC), JEDEC MS-012, .150 inch Narrow Body	Tube
FAN7171MX_F085			Tape & Reel

Note:

1. These devices passed wave soldering test by JESD22A-111.
2. A suffix as "…F085P" has been temporarily introduced in order to manage a double source strategy as Fairchild has officially announced in Aug 2014.

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Typical Application

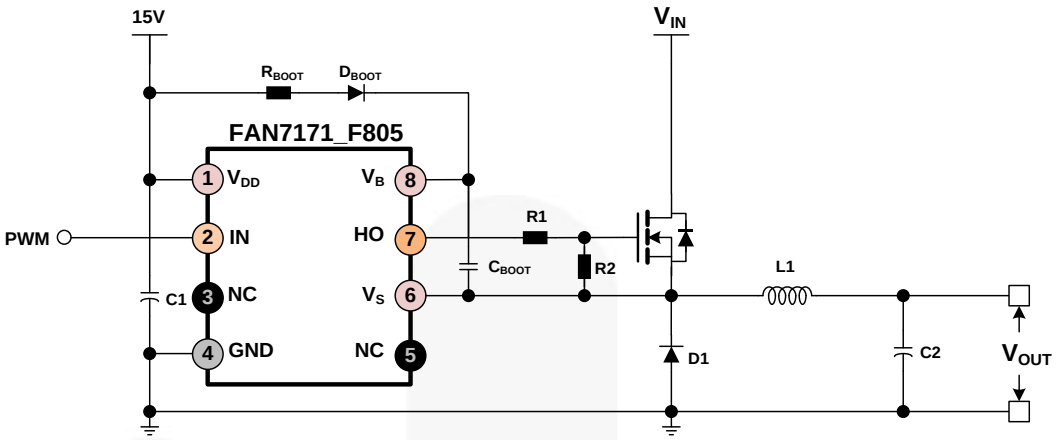

Figure 2. Typical Application

Block Diagram

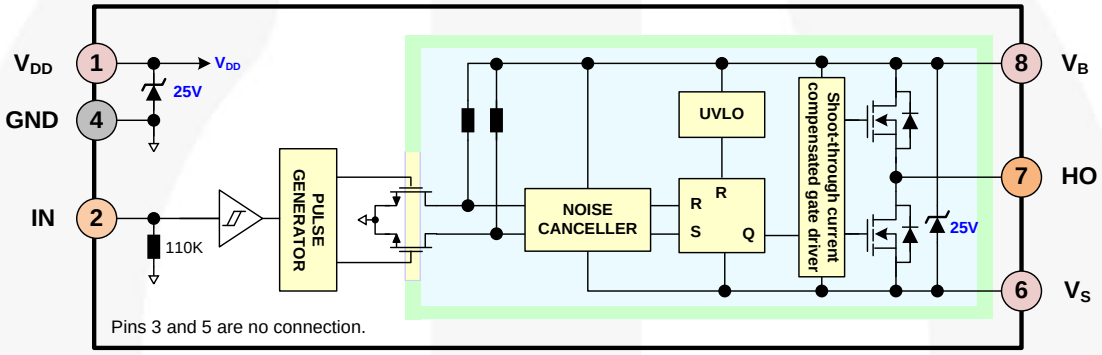

Figure 3. Block Diagram

Pin Configuration

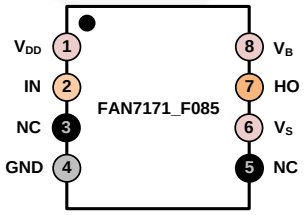

Figure 4. Pin Assignment (Top Through View)

Pin Descriptions

Pin #	Name	Description
1	V_{DD}	Supply Voltage
2	IN	Logic Input for High-Side Gate Driver Output
3	NC	No Connection
4	GND	Ground
5	NC	No Connection
6	V_S	High-Voltage Floating Supply Return
7	HO	High-Side Driver Output
8	V_B	High-Side Floating Supply

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Characteristics	Min.	Max.	Unit
V_S	High-Side Floating Offset Voltage	V_B-V_{SHUNT}	V_B+0.3	V
V_B	High-Side Floating Supply Voltage(3)	-0.3	625.0	V
V_{HO}	High-Side Floating Output Voltage	V_S-0.3	V_B+0.3	V
V_{DD}	Low-Side and Logic Supply Voltage(3)	-0.3	V_{SHUNT}	V
V_{IN}	Logic Input Voltage	-0.3	V_{DD}+0.3	V
dV_S/dt	Allowable Offset Voltage Slew Rate		±50	V/ns
P_D	Power Dissipation(4,5,6)		0.625	W
θ_{JA}	Thermal Resistance		200	°C/W
T_J	Junction Temperature	-55	150	°C
T_{STG}	Storage Temperature	-55	150	°C
T_A	Operating Ambient Temperature	-40	125	°C
ESD	Human Body Model (HBM)		1500	V
	Charge Device Model (CDM)		500	

Notes:

3. This IC contains a shunt regulator on V_{DD} and V_{BS} with a normal breakdown voltage of 25 V. Please note that this supply pin should not be driven by a low-impedance voltage source greater than the V_{SHUNT} specified in the Electrical Characteristics section.
4. Mounted on 76.2 x 114.3 x 1.6 mm PCB (FR-4 glass epoxy material).
5. Refer to the following standards:
   JESD51-2: Integral circuits thermal test method environmental conditions, natural convection, and
   JESD51-3: Low effective thermal conductivity test board for leaded surface-mount packages.
6. Do not exceed power dissipation (P_D) under any circumstances.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{BS}	High-Side Floating Supply Voltage	V_S+10	V_S+20	V
V_S	High-Side Floating Supply Offset Voltage (DC)	6-V_{DD}	600	V
	High-Side Floating Supply Offset Voltage (Transient)	-15 (~170)		
		-7 (~400)		
V_{HO}	High-Side Output Voltage	V_S	V_B	V
V_{IN}	Logic Input Voltage	GND	V_{DD}	V
V_{DD}	Supply Voltage	10	20	V

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Electrical Characteristics

V_{BIAS} (V_{DD}, V_{BS})=15 V, -40°C ≤ T_A ≤ 125°C, unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to GND. The V_O and I_O parameters are relative to V_S and are applicable to the respective output HO.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
Power Supply Section						
I_{QDD}	Quiescent V_{DD} Supply Current	V_{IN}=0 V or 5 V		25	70	µA
I_{PDD}	Operating V_{DD} Supply Current	f_{IN}=20 kHz, No Load		35	100	µA
Bootstrapped Supply Section						
V_{BSUV+}	V_{BS} Supply Under-Voltage Positive-Going Threshold Voltage	V_{BS}=Sweep	8.2	9.2	10.2	V
V_{BSUV-}	V_{BS} Supply Under-Voltage Negative-Going Threshold Voltage	V_{BS}=Sweep	7.5	8.5	9.5	V
V_{BSHYS}	V_{BS} Supply UVLO Hysteresis Voltage	V_{BS}=Sweep		0.6		V
I_{LK}	Offset Supply Leakage Current	V_B=V_S=600 V			50	µA
I_{QBS}	Quiescent V_{BS} Supply Current	V_{IN}=0 V or 5 V		60	120	µA
I_{PBS}	Operating V_{BS} Supply Current	C_{LOAD}=1 nF, f_{IN}=20 kHz, RMS Value		0.73	2.80	mA
Shunt Regulator Section						
V_{SHUNT}	V_{DD} and V_{BS} Shunt Regulator Clamping Voltage	I_{SHUNT}=5 mA	23	25		V
Input Logic Section (IN)						
V_{IH}	Logic “1” Input Voltage		2.5			V
V_{IL}	Logic “0” Input Voltage				0.8	V
I_{IN+}	Logic Input High Bias Current	V_{IN}=5 V		45	125	µA
I_{IN-}	Logic Input Low Bias Current	V_{IN}=0 V			2	µA
R_{IN}	Input Pull-down Resistance		40	110		kΩ
Gate Driver Output Section (HO)						
V_{OH}	High Level Output Voltage (V_{BIAS} - V_O)	No Load			1.5	V
V_{OL}	Low Level Output Voltage	No Load			35	mV
I_{O+}	Output High, Short-Circuit Pulsed Current(7)	V_{HO}=0 V, V_{IN}=5 V, PW ≤10 µs	3.0	4.0		A
I_{O-}	Output Low, Short-Circuit Pulsed Current(7)	V_{HO}=15 V,V_{IN}=0 V, PW ≤10 µs	3.0	4.0		A
V_S	Allowable Negative V_S Pin Voltage for IN Signal Propagation to HO			-9.8	-7.0	V

Note:

7. These parameters guaranteed by design.

Dynamic Electrical Characteristics

V_{BIAS} (V_{DD}, V_{BS}) =15 V, V_S=GND=0 V, C_L=1000 pF, and-40°C ≤ T_A ≤ 125°C, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
t_{ON}	Turn-On Propagation Delay	V_S=0 V		150	210	ns
t_{OFF}	Turn-Off Propagation Delay	V_S=0 V		150	210	ns
t_R	Turn-On Rise Time			25	50	ns
t_F	Turn-Off Fall Time			15	45	ns

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Typical Performance Characteristics

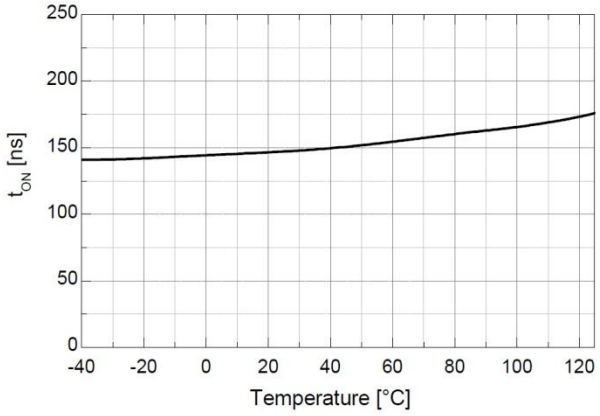

Figure 5. Turn-On Propagation Delay vs. Temperature

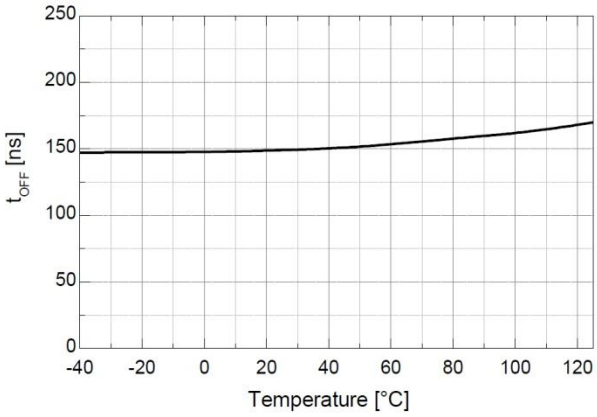

Figure 6. Turn-Off Propagation Delay vs. Temperature

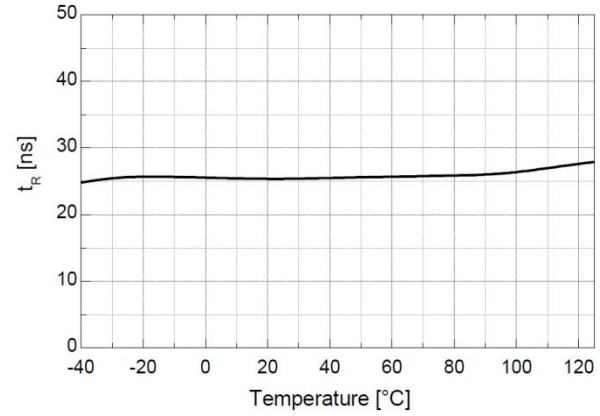

Figure 7. Turn-On Rise Time vs. Temperature

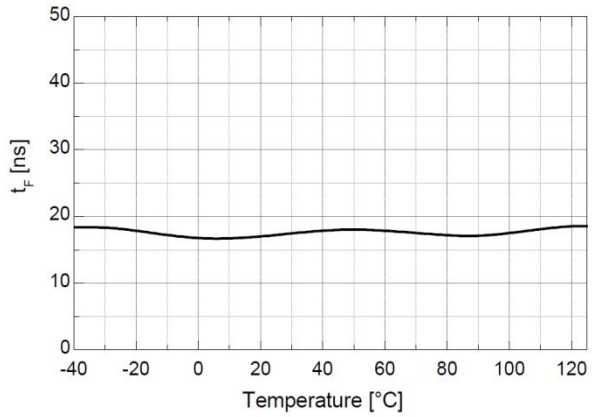

Figure 8. Turn-Off Fall Time vs. Temperature

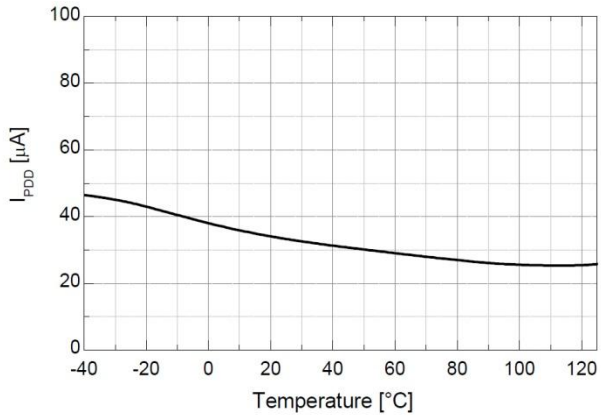

Figure 9. Operating V_{DD} Supply Current vs. Temperature

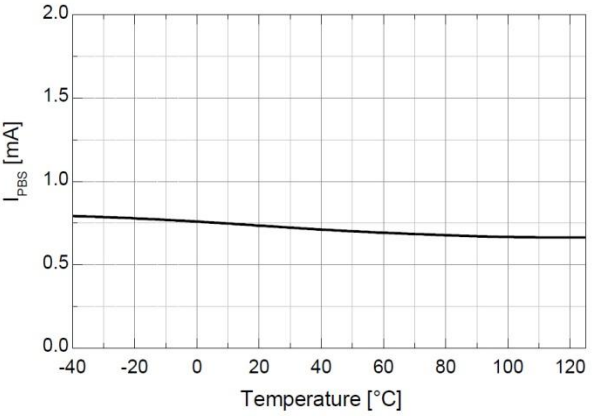

Figure 10. Operating V_{BS} Supply Current vs. Temperature

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Typical Performance Characteristics

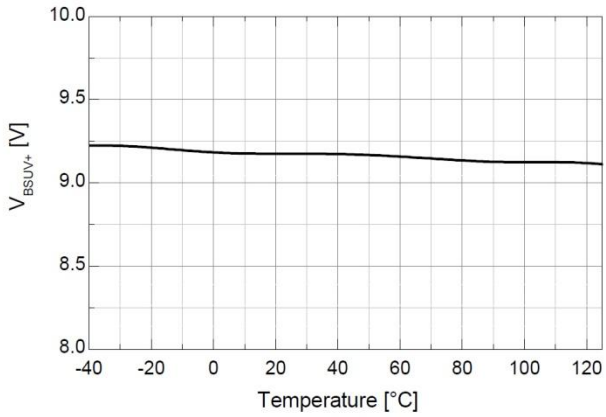


Figure 11. V_{BS} UVLO+ vs. Temperature

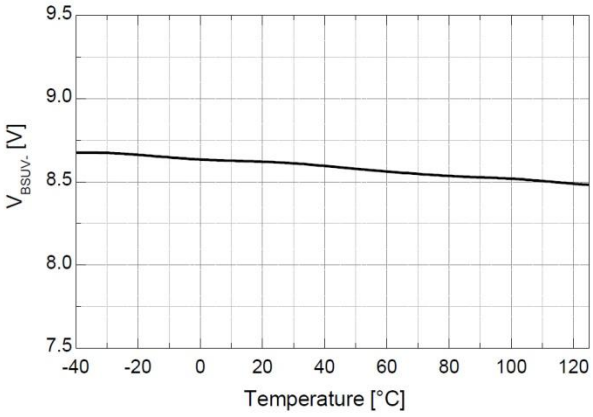


Figure 12. V_{BS} UVLO- vs. Temperature

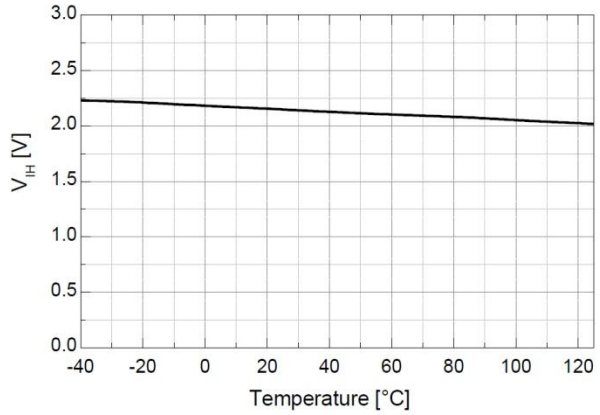


Figure 13. Logic High Input Voltage vs. Temperature

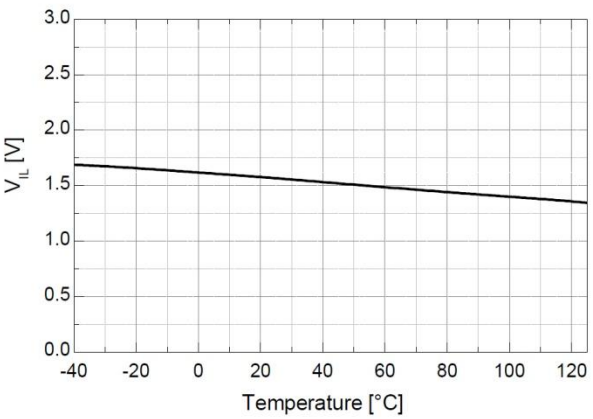


Figure 14. Logic Low Input Voltage vs. Temperature

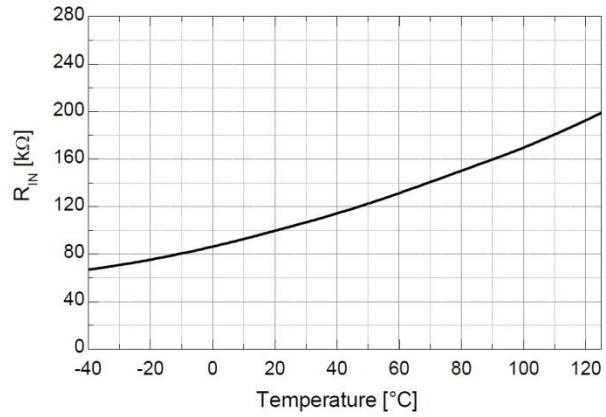


Figure 15. Input Pull-Down Resistance vs. Temperature

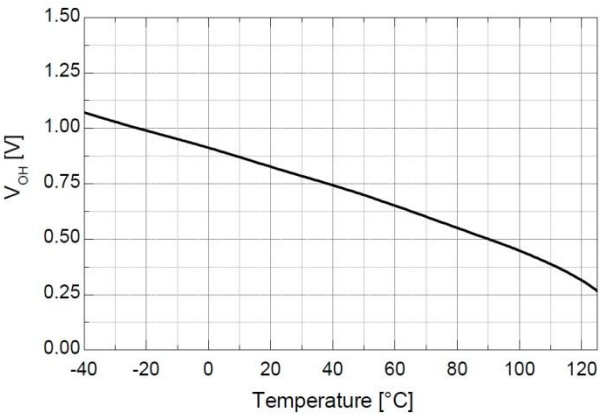


Figure 16. High-Level Output Voltage vs. Temperature

Typical Performance Characteristics

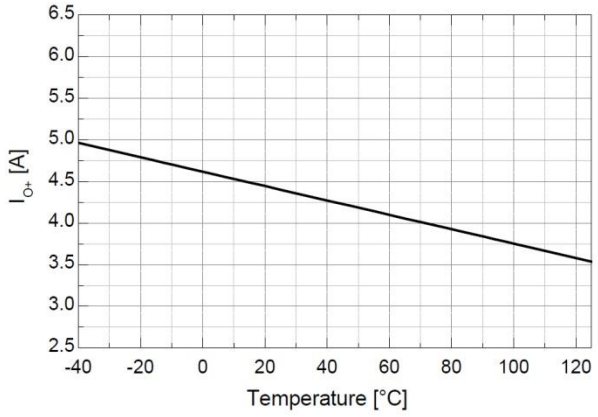


Figure 17. Output High, Short-Circuit Pulsed Current vs. Temperature

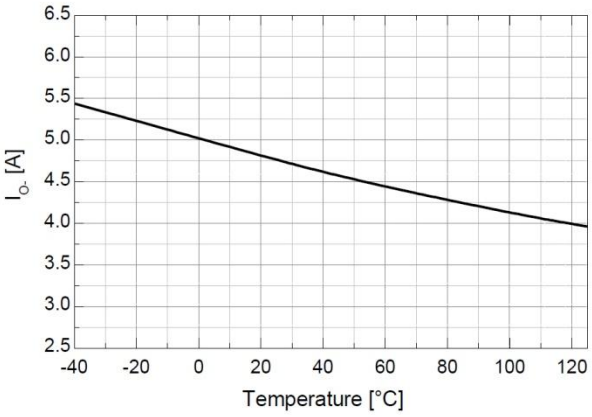


Figure 18. Output Low, Short-Circuit Pulsed Current vs. Temperature

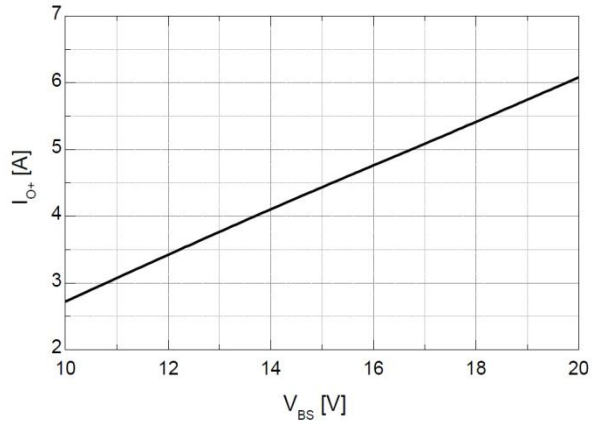


Figure 19. Output High, Short-Circuit Pulsed Current vs. Supply Voltage

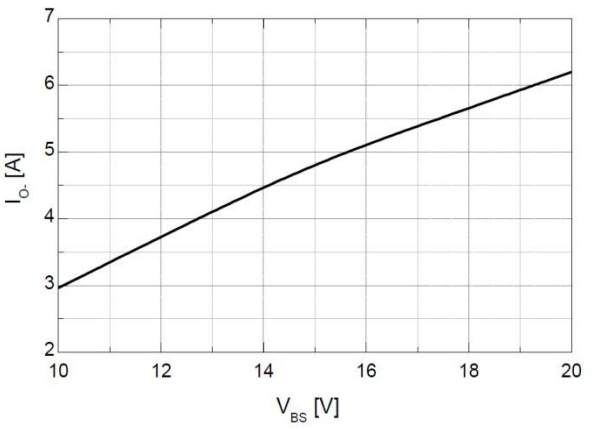


Figure 20. Output Low, Short-Circuit Pulsed Current vs. Supply Voltage

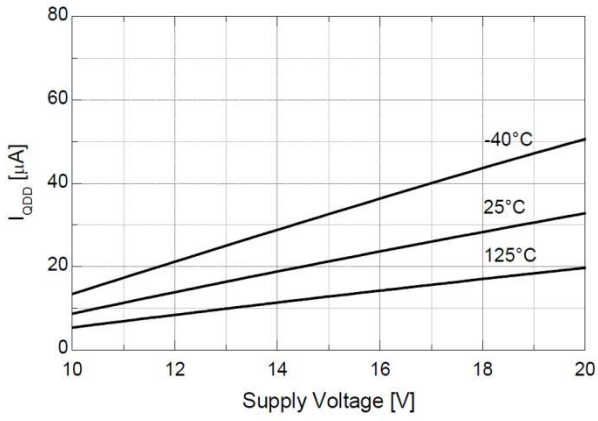


Figure 21. Quiescent V_{DD} Supply Current vs. Supply Voltage

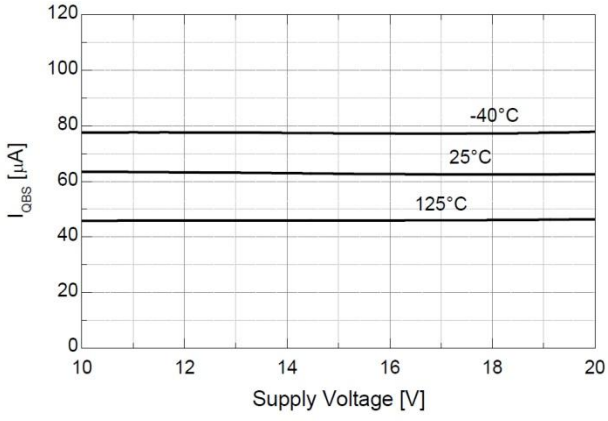


Figure 22. Quiescent V_{BS} Supply Current vs. Supply Voltage

Switching Time Definitions

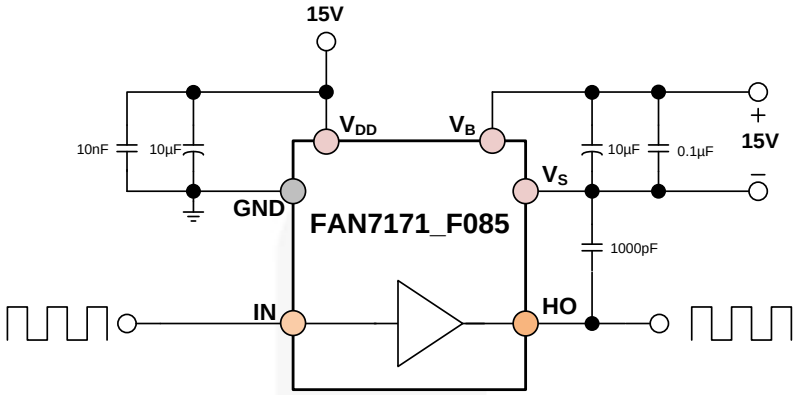


Figure 23. Switching Time Test Circuit (Referenced 8-SOIC)

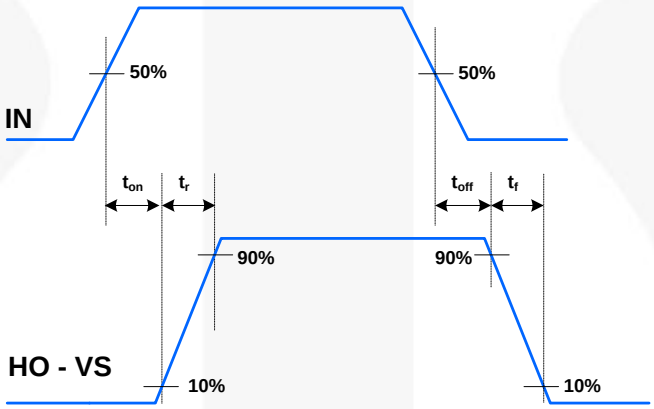


Figure 24. Switching Time Waveform Definitions

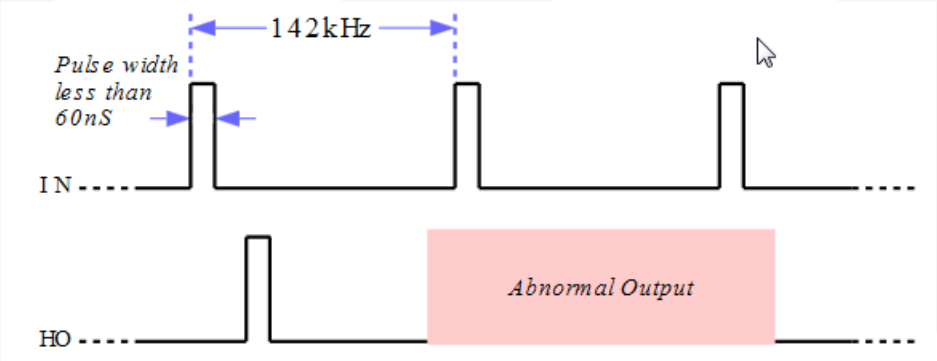


Figure 25. Abnormal Output Waveform with Short Pulse Width

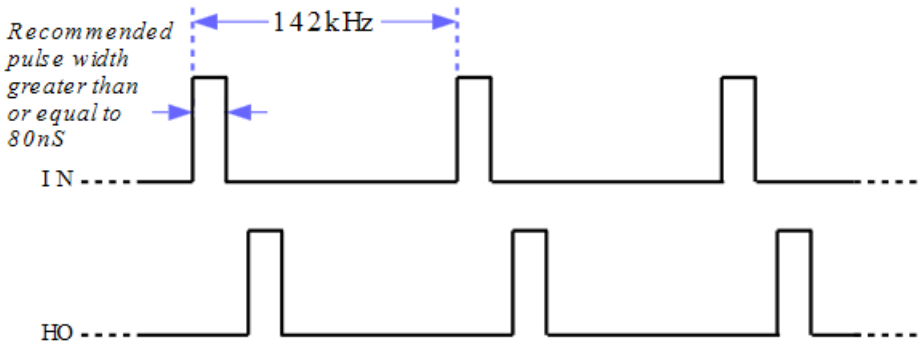
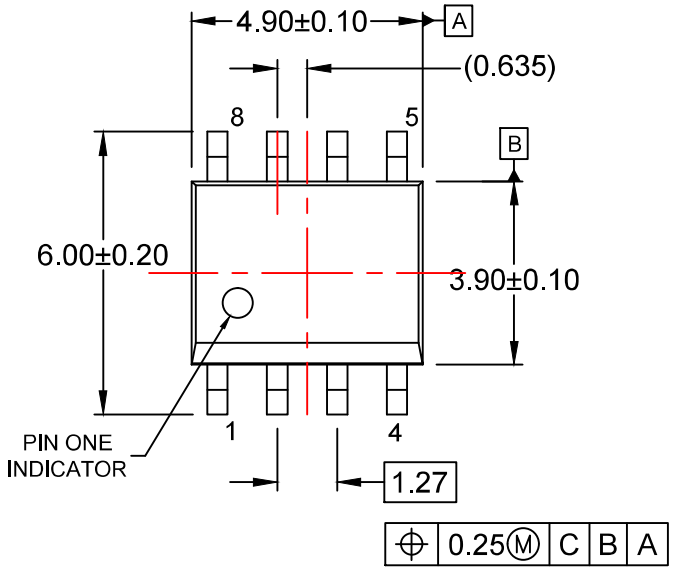
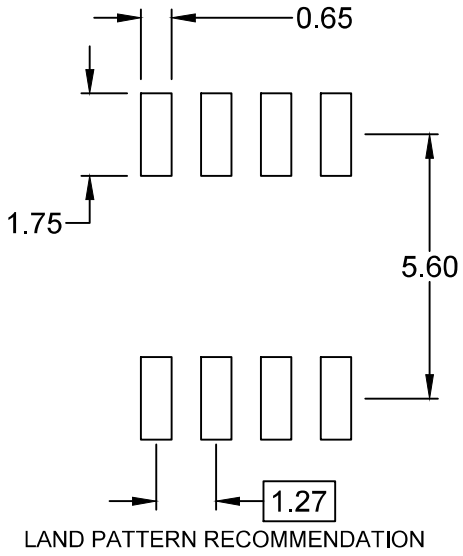
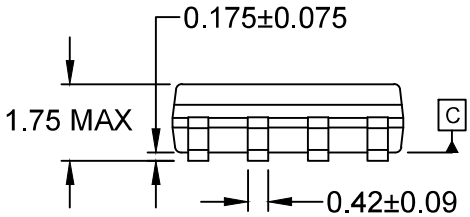


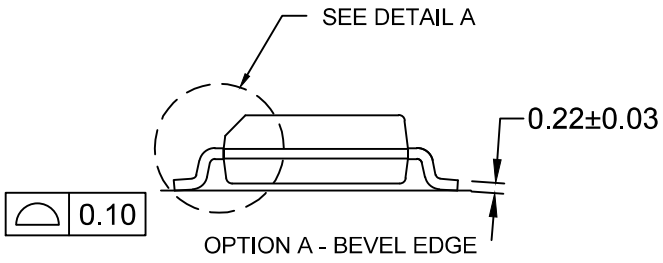
Figure 26. Recommendation of Pulse Width Output Waveform



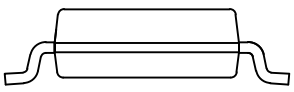


LAND PATTERN RECOMMENDATION

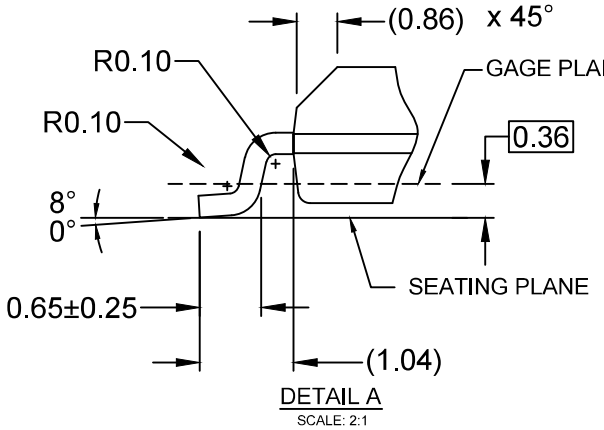




OPTION A - BEVEL EDGE



OPTION B - NO BEVEL EDGE



DETAIL A
SCALE: 2:1

NOTES:

A) THIS PACKAGE CONFORMS TO JEDEC MS-012, VARIATION AA.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
D) LANDPATTERN STANDARD: SOIC127P600X175-8M
E) DRAWING FILENAME: M08Arev16

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